



566.40894X00

**EXPEDITED PROCEDURE PURSUANT
TO 37 CFR §1.116 REQUESTED**

#18
Amended
J. My
9/25/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: K. HORIKOSHI et al
Serial No.: 09/988,585
Filed: November 20, 2001
For: THIN-FILM TRANSISTOR AND METHOD OF
MANUFACTURING THE SAME
Group: 2811
Examiner: T. TRAN

AMENDMENT AFTER FINAL

MS: After Final

Commissioner For Patents
POB 1450
Alexandria, VA 22313-1450

June 27 2003

RECEIVED
JUN 30 2003
TECHNOLOGY CENTER 2800

Sir:

In response to the Final Office Action, dated February 27, 2003, the period of response for which extension of time is requested in the attached Petition for Extension of Time, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

IN THE CLAIMS:

Please **cancel** claim 2 without prejudice or disclaimer and **amend** claims 1 and 9 to read as follows:

1. (Twice Amended) A thin-film transistor comprising:
a glass substrate; and